Tapered Amplifier

EYP-TPA-0780-02000-4006-CMT04-0000

General Product Information				
Product	Application			
780 nm Tapered Amplifier	Spectroscopy			
C-Mount Package	Metrology			
	Fiber Coupling			



Absolute Maximum Ratings

	Symbol	Unit	min	typ	max
Storage Temperature	T_S	°C	-40		85
Operational Temperature at Case	T_C	°C	0		50
Current	I _F	А			5
Reverse Voltage	V_R	V			0
Output Power	Popt	W			2.2

non condensing
non condensing
Stress in excess of the Absolute Maximum Ratings can
cause permanent damage to the device. Operation at the
Absolute Maximum Rating for extended periods of time
can adversely affect the device realibility and may lead to
reduced operational life.

Recommended Operational Conditions

	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	5		40
Forward Current	$I_{F \; Gain}$	Α			4
Output Power	P_{opt}	W			2

non condensing	Ξ
with proper injection from a seed laser	

Characteristics at T_{amb} 25 °C at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	770	780	785
Gain Width (FWHM)	$\Delta\lambda$	nm	5	10	
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.25	
Amplification		dB		18	
Minimum Input Power	P_{min}	mW		10	
Saturation Power	P_{Sat}	mW		50	

Measurement Conditions / Comments	



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Characteristics at T _{amb} 25 °C at Begin Of Life					
Parameter	Symbol	Unit	min	typ	max
Operational Current @ P _{opt} = 2 W	I _{op Gain}	А			4
Output Power @ I _F = 4 A	P _{opt}	W	2		
Operational Current @ P _{opt} min	I _{op Gain}	mA		170	200
Sidemode Supression Ratio	SMSR	dB	30	45	
Cavity Length	L	μm		4000	
Input Aperture (at rear side)	d _{input}	μm		3	
Output Aperture (at front side)	d _{output}	μm		210	
Astigmatism	А	μm			600
Divergence parallel (FWHM)	$\Theta_{ }$	0		10	
Divergence perpendicular (FWHM)	Θ_{\perp}	0		33	
Polarization				TM	

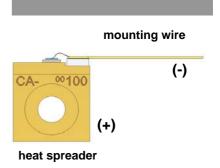
Measurement Conditions / Comments
with proper injection from a seed laser
with proper injection from a seed laser
ECH PLATE C
E field perpendicular to junction plane

Tapered Amplifier

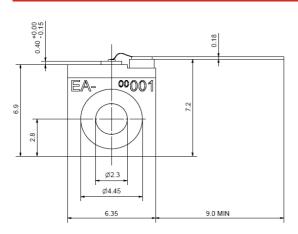
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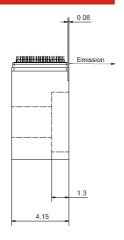
Package Dimensions					
	Symbol	Unit	min	typ	max
Emission Plane	I	mm	7.05	7.20	7.35
C-Mount Thickness	d	mm		4.15	

Package Pinout		
Cathode (-) Anode (+)	Mounting Wire	
Anode (+)	Housing	



Package Drawings



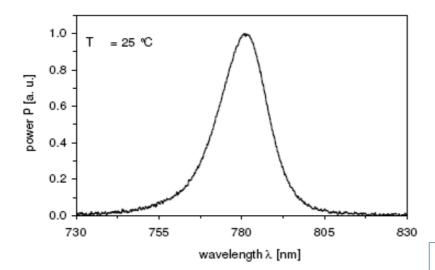


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Typical Measurement Results

Spectrum measured w/o injection



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Ordering Information:



800 Village Walk #316 Guilford, CT 06437 Ph: 203-401-8093

Email orders to: sales@xsoptix.com
Fax orders to: 800-878-7282

Unpackaging, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The TPA diode type is known to be sensitive against thermal stress. It should not be operated without appropriate injection from a seed laser. Operating at moderate temperatures on propper heat sinks willl contribute to a long lifetime of the diode.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase thread to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.

